

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S24	195	(257/692).ccls. and @ad<"20021230" and ((redistribut\$ or passive or induct\$4 or capacit\$4) with (wir\$4))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/10/01 20:44
S29	218	(257/692).ccls. and @ad<"20021230" and ((redistribut\$5 or passive or induct\$4 or capacit\$4) with (wir\$4 or trac\$3))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/10/01 20:44
S25	214	(257/773).ccls. and @ad<"20021230" and ((redistribut\$ or passive or induct\$4 or capacit\$4) with (wir\$4))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/10/01 20:45
S30	237	(257/773).ccls. and @ad<"20021230" and ((redistribut\$5 or passive or induct\$4 or capacit\$4) with (wir\$4 or trac\$3))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/10/01 20:45
S26	179	(257/786).ccls. and @ad<"20021230" and ((redistribut\$ or passive or induct\$4 or capacit\$4) with (wir\$4))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/10/01 21:14
S32	211	(257/786).ccls. and @ad<"20021230" and ((redistribut\$5 or passive or induct\$4 or capacit\$4) with (wir\$4 or trac\$3))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/10/01 21:14
S27	89	(257/528).ccls. and @ad<"20021230" and ((redistribut\$ or passive or induct\$4 or capacit\$4) with (wir\$4))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/10/01 21:26
S33	106	(257/528).ccls. and @ad<"20021230" and ((redistribut\$5 or passive or induct\$4 or capacit\$4) with (wir\$4 or trac\$3))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/10/01 21:27
S28	573	(257/531 or 257/532).ccls. and @ad<"20021230" and ((redistribut\$ or passive or induct\$4 or capacit\$4) with (wir\$4))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/10/01 21:33

S34	653	(257/531 or 257/532).ccls. and @ad<"20021230" and ((redistribut\$5 or passive or induct\$4 or capacit\$4) with (wir\$4 or trac\$3))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/10/01 21:33
S22	385	semiconductor and ((active or circuit) near5 (area or region or portion)) and (((wir\$3 near5 (area or region or portion)) with (peripher\$3 or edge or outside)) same (passive or capacit\$4 or induct\$4)) and (chip or die or substrate) and @ad<"20021230"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/10/01 22:47
S35	375	semiconductor and ((active or circuit) near5 (area or region or portion)) and (((wir\$3 near5 (area or region or portion)) with (peripher\$3 or edge or outside)) same (passive or capacit\$4)) and @ad<"20021230"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/10/01 22:49